# E·XFL

# Intel - EPF10K50STC144-2X Datasheet



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#### Understanding <u>Embedded - FPGAs (Field</u> <u>Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

## **Applications of Embedded - FPGAs**

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

#### Details

Product Status	Obsolete
Number of LABs/CLBs	360
Number of Logic Elements/Cells	2880
Total RAM Bits	40960
Number of I/O	102
Number of Gates	199000
Voltage - Supply	2.375V ~ 2.625V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 70°C (TA)
Package / Case	144-LQFP
Supplier Device Package	144-TQFP (20x20)
Purchase URL	https://www.e-xfl.com/product-detail/intel/epf10k50stc144-2x

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The EAB can also be used for bidirectional, dual-port memory applications where two ports read or write simultaneously. To implement this type of dual-port memory, two EABs are used to support two simultaneous read or writes.

Alternatively, one clock and clock enable can be used to control the input registers of the EAB, while a different clock and clock enable control the output registers (see Figure 2).



#### Notes:

- (1) All registers can be asynchronously cleared by EAB local interconnect signals, global signals, or the chip-wide reset.
- (2) EPF10K30E and EPF10K50E devices have 88 EAB local interconnect channels; EPF10K100E, EPF10K130E, and EPF10K200E devices have 104 EAB local interconnect channels.



# Figure 11. FLEX 10KE LE Operating Modes









#### **Clearable Counter Mode**



In addition to the six clear and preset modes, FLEX 10KE devices provide a chip-wide reset pin that can reset all registers in the device. Use of this feature is set during design entry. In any of the clear and preset modes, the chip-wide reset overrides all other signals. Registers with asynchronous presets may be preset when the chip-wide reset is asserted. Inversion can be used to implement the asynchronous preset. Figure 12 shows examples of how to setup the preset and clear inputs for the desired functionality.







# I/O Element

An IOE contains a bidirectional I/O buffer and a register that can be used either as an input register for external data that requires a fast setup time, or as an output register for data that requires fast clock-to-output performance. In some cases, using an LE register for an input register will result in a faster setup time than using an IOE register. IOEs can be used as input, output, or bidirectional pins. For bidirectional registered I/O implementation, the output register should be in the IOE, and the data input and output enable registers should be LE registers placed adjacent to the bidirectional pin. The Altera Compiler uses the programmable inversion option to invert signals from the row and column interconnect automatically where appropriate. Figure 15 shows the bidirectional I/O registers.

Figure 15. FLEX 10KE Bidirectional I/O Registers



#### Note:

(1) All FLEX 10KE devices (except the EPF10K50E and EPF10K200E devices) have a programmable input delay buffer on the input path.

#### **Altera Corporation**

# PCI Pull-Up Clamping Diode Option

FLEX 10KE devices have a pull-up clamping diode on every I/O, dedicated input, and dedicated clock pin. PCI clamping diodes clamp the signal to the  $V_{\rm CCIO}$  value and are required for 3.3-V PCI compliance. Clamping diodes can also be used to limit overshoot in other systems.

Clamping diodes are controlled on a pin-by-pin basis. When  $V_{CCIO}$  is 3.3 V, a pin that has the clamping diode option turned on can be driven by a 2.5-V or 3.3-V signal, but not a 5.0-V signal. When  $V_{CCIO}$  is 2.5 V, a pin that has the clamping diode option turned on can be driven by a 2.5-V signal, but not a 3.3-V or 5.0-V signal. Additionally, a clamping diode can be activated for a subset of pins, which would allow a device to bridge between a 3.3-V PCI bus and a 5.0-V device.

# **Slew-Rate Control**

The output buffer in each IOE has an adjustable output slew rate that can be configured for low-noise or high-speed performance. A slower slew rate reduces system noise and adds a maximum delay of 4.3 ns. The fast slew rate should be used for speed-critical outputs in systems that are adequately protected against noise. Designers can specify the slew rate pin-by-pin or assign a default slew rate to all pins on a device-wide basis. The slow slew rate setting affects the falling edge of the output.

# **Open-Drain Output Option**

FLEX 10KE devices provide an optional open-drain output (electrically equivalent to open-collector output) for each I/O pin. This open-drain output enables the device to provide system-level control signals (e.g., interrupt and write enable signals) that can be asserted by any of several devices. It can also provide an additional wired-OR plane.

# MultiVolt I/O Interface

The FLEX 10KE device architecture supports the MultiVolt I/O interface feature, which allows FLEX 10KE devices in all packages to interface with systems of differing supply voltages. These devices have one set of  $V_{CC}$  pins for internal operation and input buffers (VCCINT), and another set for I/O output drivers (VCCIO).

The VCCINT pins must always be connected to a 2.5-V power supply. With a 2.5-V V<sub>CCINT</sub> level, input voltages are compatible with 2.5-V, 3.3-V, and 5.0-V inputs. The VCCIO pins can be connected to either a 2.5-V or 3.3-V power supply, depending on the output requirements. When the VCCIO pins are connected to a 2.5-V power supply, the output levels are compatible with 2.5-V systems. When the VCCIO pins are connected to a 3.3-V power supply, the output high is at 3.3 V and is therefore compatible with 3.3-V or 5.0-V systems. Devices operating with V<sub>CCIO</sub> levels higher than 3.0 V achieve a faster timing delay of  $t_{OD2}$  instead of  $t_{OD1}$ .

Table 14. FLEX 10KE MultiVolt I/O Support						
V <sub>CCIO</sub> (V)	Inp	Input Signal (V) Output Signal (V)				
	2.5	3.3	5.0	2.5	3.3	5.0
2.5	~	✓(1)	✓ (1)	~		
3.3	$\checkmark$	$\checkmark$	✓ (1)	✓(2)	$\checkmark$	~

Table 14 summarizes FLEX 10KE MultiVolt I/O support.

#### Notes:

(1) The PCI clamping diode must be disabled to drive an input with voltages higher than  $V_{\rm CCIO}$ .

(2) When  $V_{CCIO}$  = 3.3 V, a FLEX 10KE device can drive a 2.5-V device that has 3.3-V tolerant inputs.

Open-drain output pins on FLEX 10KE devices (with a pull-up resistor to the 5.0-V supply) can drive 5.0-V CMOS input pins that require a  $V_{\rm IH}$  of 3.5 V. When the open-drain pin is active, it will drive low. When the pin is inactive, the trace will be pulled up to 5.0 V by the resistor. The open-drain pin will only drive low or tri-state; it will never drive high. The rise time is dependent on the value of the pull-up resistor and load impedance. The I<sub>OL</sub> current specification should be considered when selecting a pull-up resistor.

## Power Sequencing & Hot-Socketing

Because FLEX 10KE devices can be used in a mixed-voltage environment, they have been designed specifically to tolerate any possible power-up sequence. The  $V_{\rm CCIO}$  and  $V_{\rm CCINT}$  power planes can be powered in any order.

Signals can be driven into FLEX 10KE devices before and during power up without damaging the device. Additionally, FLEX 10KE devices do not drive out during power up. Once operating conditions are reached, FLEX 10KE devices operate as specified by the user.

# IEEE Std. 1149.1 (JTAG) Boundary-Scan Support

All FLEX 10KE devices provide JTAG BST circuitry that complies with the IEEE Std. 1149.1-1990 specification. FLEX 10KE devices can also be configured using the JTAG pins through the BitBlaster or ByteBlasterMV download cable, or via hardware that uses the Jam<sup>™</sup> STAPL programming and test language. JTAG boundary-scan testing can be performed before or after configuration, but not during configuration. FLEX 10KE devices support the JTAG instructions shown in Table 15.

Table 15. FLEX 10KE JTAG Instructions				
JTAG Instruction	Description			
SAMPLE/PRELOAD	Allows a snapshot of signals at the device pins to be captured and examined during normal device operation, and permits an initial data pattern to be output at the device pins.			
EXTEST	Allows the external circuitry and board-level interconnections to be tested by forcing a test pattern at the output pins and capturing test results at the input pins.			
BYPASS	Places the 1-bit bypass register between the TDI and TDO pins, which allows the BST data to pass synchronously through a selected device to adjacent devices during normal device operation.			
USERCODE	Selects the user electronic signature (USERCODE) register and places it between the TDI and TDO pins, allowing the USERCODE to be serially shifted out of TDO.			
IDCODE	Selects the IDCODE register and places it between TDI and TDO, allowing the IDCODE to be serially shifted out of TDO.			
ICR Instructions	These instructions are used when configuring a FLEX 10KE device via JTAG ports with a BitBlaster or ByteBlasterMV download cable, or using a Jam File ( <b>.jam</b> ) or Jam Byte-Code File ( <b>.jbc</b> ) via an embedded processor.			

The instruction register length of FLEX 10KE devices is 10 bits. The USERCODE register length in FLEX 10KE devices is 32 bits; 7 bits are determined by the user, and 25 bits are pre-determined. Tables 16 and 17 show the boundary-scan register length and device IDCODE information for FLEX 10KE devices.

Table 16. FLEX 10KE Boundary-Scan Register Length				
Device	Boundary-Scan Register Length			
EPF10K30E	690			
EPF10K50E	798			
EPF10K50S				
EPF10K100E	1,050			
EPF10K130E	1,308			
EPF10K200E	1,446			
EPF10K200S				

Figure 20 shows the timing requirements for the JTAG signals.



Figure 20. FLEX 10KE JTAG Waveforms

# Table 18 shows the timing parameters and values for FLEX 10KE devices.

Table 18. FLEX 10KE JTAG Timing Parameters & Values					
Symbol	Parameter	Min	Мах	Unit	
t <sub>JCP</sub>	TCK clock period	100		ns	
t <sub>JCH</sub>	TCK clock high time	50		ns	
t <sub>JCL</sub>	TCK clock low time	50		ns	
t <sub>JPSU</sub>	JTAG port setup time	20		ns	
t <sub>JPH</sub>	JTAG port hold time	45		ns	
t <sub>JPCO</sub>	JTAG port clock to output		25	ns	
t <sub>JPZX</sub>	JTAG port high impedance to valid output		25	ns	
t <sub>JPXZ</sub>	JTAG port valid output to high impedance		25	ns	
t <sub>JSSU</sub>	Capture register setup time	20		ns	
t <sub>JSH</sub>	Capture register hold time	45		ns	
t <sub>JSCO</sub>	Update register clock to output		35	ns	
t <sub>JSZX</sub>	Update register high impedance to valid output		35	ns	
t <sub>JSXZ</sub>	Update register valid output to high impedance		35	ns	

Table 23. FLEX 10KE Device Capacitance     Note (14)						
Symbol	Parameter	Conditions	Min	Max	Unit	
CIN	Input capacitance	V <sub>IN</sub> = 0 V, f = 1.0 MHz		10	pF	
CINCLK	Input capacitance on dedicated clock pin	V <sub>IN</sub> = 0 V, f = 1.0 MHz		12	pF	
C <sub>OUT</sub>	Output capacitance	V <sub>OUT</sub> = 0 V, f = 1.0 MHz		10	pF	

#### Notes to tables:

- (1) See the Operating Requirements for Altera Devices Data Sheet.
- (2) Minimum DC input voltage is -0.5 V. During transitions, the inputs may undershoot to -2.0 V for input currents less than 100 mA and periods shorter than 20 ns.
- (3) Numbers in parentheses are for industrial-temperature-range devices.
- (4) Maximum  $V_{CC}$  rise time is 100 ms, and  $V_{CC}$  must rise monotonically.
- (5) All pins, including dedicated inputs, clock, I/O, and JTAG pins, may be driven before  $V_{CCINT}$  and  $V_{CCIO}$  are powered.
- (6) Typical values are for  $T_A = 25^{\circ}$  C,  $V_{CCINT} = 2.5$  V, and  $V_{CCIO} = 2.5$  V or 3.3 V.
- (7) These values are specified under the FLEX 10KE Recommended Operating Conditions shown in Tables 20 and 21.
  (8) The FLEX 10KE input buffers are compatible with 2.5-V, 3.3-V (LVTTL and LVCMOS), and 5.0-V TTL and CMOS
- signals. Additionally, the input buffers are 3.3-V PCI compliant when  $V_{CCIO}$  and  $V_{CCINT}$  meet the relationship shown in Figure 22.
- (9) The I<sub>OH</sub> parameter refers to high-level TTL, PCI, or CMOS output current.
- (10) The I<sub>OL</sub> parameter refers to low-level TTL, PCI, or CMOS output current. This parameter applies to open-drain pins as well as output pins.
- (11) This value is specified for normal device operation. The value may vary during power-up.
- (12) This parameter applies to -1 speed-grade commercial-temperature devices and -2 speed-grade-industrial temperature devices.
- (13) Pin pull-up resistance values will be lower if the pin is driven higher than  $V_{CCIO}$  by an external source.
- (14) Capacitance is sample-tested only.

Figure 22 shows the required relationship between  $V_{CCIO}$  and  $V_{CCINT}$  for 3.3-V PCI compliance.



Figure 23 shows the typical output drive characteristics of FLEX 10KE devices with 3.3-V and 2.5-V V<sub>CCIO</sub>. The output driver is compliant to the 3.3-V *PCI Local Bus Specification*, *Revision 2.2* (when VCCIO pins are connected to 3.3 V). FLEX 10KE devices with a -1 speed grade also comply with the drive strength requirements of the *PCI Local Bus Specification*, *Revision 2.2* (when VCCINT pins are powered with a minimum supply of 2.375 V, and VCCIO pins are connected to 3.3 V). Therefore, these devices can be used in open 5.0-V PCI systems.

Table 24. LE Timing Microparameters (Part 2 of 2)       Note (1)					
Symbol	Symbol Parameter				
t <sub>CLR</sub>	LE register clear delay				
t <sub>CH</sub>	Minimum clock high time from clock pin				
t <sub>CL</sub>	Minimum clock low time from clock pin				

Table 25. IOE Timing Microparameters     Note (1)				
Symbol	Parameter	Conditions		
t <sub>IOD</sub>	IOE data delay			
t <sub>IOC</sub>	IOE register control signal delay			
t <sub>IOCO</sub>	IOE register clock-to-output delay			
t <sub>IOCOMB</sub>	IOE combinatorial delay			
t <sub>IOSU</sub>	IOE register setup time for data and enable signals before clock; IOE register recovery time after asynchronous clear			
t <sub>IOH</sub>	IOE register hold time for data and enable signals after clock			
t <sub>IOCLR</sub>	IOE register clear time			
t <sub>OD1</sub>	Output buffer and pad delay, slow slew rate = off, $V_{CCIO}$ = 3.3 V	C1 = 35 pF (2)		
t <sub>OD2</sub>	Output buffer and pad delay, slow slew rate = off, $V_{CCIO}$ = 2.5 V	C1 = 35 pF (3)		
t <sub>OD3</sub>	Output buffer and pad delay, slow slew rate = on	C1 = 35 pF (4)		
t <sub>XZ</sub>	IOE output buffer disable delay			
t <sub>ZX1</sub>	IOE output buffer enable delay, slow slew rate = off, $V_{CCIO}$ = 3.3 V	C1 = 35 pF (2)		
t <sub>ZX2</sub>	IOE output buffer enable delay, slow slew rate = off, $V_{CCIO}$ = 2.5 V	C1 = 35 pF (3)		
t <sub>ZX3</sub>	IOE output buffer enable delay, slow slew rate = on	C1 = 35 pF (4)		
t <sub>INREG</sub>	IOE input pad and buffer to IOE register delay			
t <sub>IOFD</sub>	IOE register feedback delay			
t <sub>INCOMB</sub>	IOE input pad and buffer to FastTrack Interconnect delay			

Table 27. EAE	<b>3 Timing Macroparameters</b> Note (1), (6)				
Symbol	Parameter	Conditions			
t <sub>EABAA</sub>	EAB address access delay				
t <sub>EABRCCOMB</sub>	EAB asynchronous read cycle time				
t <sub>EABRCREG</sub>	EAB synchronous read cycle time				
t <sub>EABWP</sub>	EAB write pulse width				
t <sub>EABWCCOMB</sub>	EAB asynchronous write cycle time				
t <sub>EABWCREG</sub>	EAB synchronous write cycle time				
t <sub>EABDD</sub>	EAB data-in to data-out valid delay				
t <sub>EABDATACO</sub>	EAB clock-to-output delay when using output registers				
t <sub>EABDATASU</sub>	EAB data/address setup time before clock when using input register				
t <sub>EABDATAH</sub>	EAB data/address hold time after clock when using input register				
t <sub>EABWESU</sub>	EAB WE setup time before clock when using input register				
t <sub>EABWEH</sub>	EAB WE hold time after clock when using input register				
t <sub>EABWDSU</sub>	EAB data setup time before falling edge of write pulse when not using input registers				
t <sub>EABWDH</sub>	EAB data hold time after falling edge of write pulse when not using input registers				
t <sub>EABWASU</sub>	EAB address setup time before rising edge of write pulse when not using				
	input registers				
t <sub>EABWAH</sub>	EAB address hold time after falling edge of write pulse when not using input				
	registers				
t <sub>EABWO</sub>	EAB write enable to data output valid delay				

Table 30. External Bidirectional Timing Parameters         Note (9)				
Symbol	Parameter	Conditions		
<sup>t</sup> insubidir	Setup time for bi-directional pins with global clock at same-row or same- column LE register			
t <sub>INHBIDIR</sub>	Hold time for bidirectional pins with global clock at same-row or same-column LE register			
t <sub>INH</sub>	Hold time with global clock at IOE register			
t <sub>OUTCOBIDIR</sub>	Clock-to-output delay for bidirectional pins with global clock at IOE register	C1 = 35 pF		
t <sub>XZBIDIR</sub>	Synchronous IOE output buffer disable delay	C1 = 35 pF		
t <sub>ZXBIDIR</sub>	Synchronous IOE output buffer enable delay, slow slew rate= off	C1 = 35 pF		

#### Notes to tables:

- (1) Microparameters are timing delays contributed by individual architectural elements. These parameters cannot be measured explicitly.
- (2) Operating conditions: VCCIO =  $3.3 \text{ V} \pm 10\%$  for commercial or industrial use.
- (3) Operating conditions: VCCIO = 2.5 V ±5% for commercial or industrial use in EPF10K30E, EPF10K50S, EPF10K100E, EPF10K130E, and EPF10K200S devices.
- (4) Operating conditions: VCCIO = 3.3 V.
- (5) Because the RAM in the EAB is self-timed, this parameter can be ignored when the WE signal is registered.
- (6) EAB macroparameters are internal parameters that can simplify predicting the behavior of an EAB at its boundary; these parameters are calculated by summing selected microparameters.
- (7) These parameters are worst-case values for typical applications. Post-compilation timing simulation and timing analysis are required to determine actual worst-case performance.
- (8) Contact Altera Applications for test circuit specifications and test conditions.
- (9) This timing parameter is sample-tested only.
- (10) This parameter is measured with the measurement and test conditions, including load, specified in the PCI Local Bus Specification, revision 2.2.

FLEX 10KE Embedded Programmable	e Logic Devices	Data Sheet
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Table 41. EPF10K50E Device EAB Internal Timing Macroparameters       Note (1)							
Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
t <sub>EABAA</sub>		6.4		7.6		10.2	ns
t <sub>EABRCOMB</sub>	6.4		7.6		10.2		ns
t <sub>EABRCREG</sub>	4.4		5.1		7.0		ns
t <sub>EABWP</sub>	2.5		2.9		3.9		ns
t <sub>EABWCOMB</sub>	6.0		7.0		9.5		ns
t <sub>EABWCREG</sub>	6.8		7.8		10.6		ns
t <sub>EABDD</sub>		5.7		6.7		9.0	ns
t <sub>EABDATACO</sub>		0.8		0.9		1.3	ns
t <sub>EABDATASU</sub>	1.5		1.7		2.3		ns
t <sub>EABDATAH</sub>	0.0		0.0		0.0		ns
t <sub>EABWESU</sub>	1.3		1.4		2.0		ns
t <sub>EABWEH</sub>	0.0		0.0		0.0		ns
t <sub>EABWDSU</sub>	1.5		1.7		2.3		ns
t <sub>EABWDH</sub>	0.0		0.0		0.0		ns
t <sub>EABWASU</sub>	3.0		3.6		4.8		ns
t <sub>EABWAH</sub>	0.5		0.5		0.8		ns
t <sub>EABWO</sub>		5.1		6.0		8.1	ns

Table 42. EPF10K50E Device Interconnect Timing Microparameters       Note (1)									
Symbol	-1 Speed Grade		-2 Spee	-2 Speed Grade		d Grade	Unit		
	Min	Max	Min	Max	Min	Max			
t <sub>DIN2IOE</sub>		3.5		4.3		5.6	ns		
t <sub>DIN2LE</sub>		2.1		2.5		3.4	ns		
t <sub>DIN2DATA</sub>		2.2		2.4		3.1	ns		
t <sub>DCLK2IOE</sub>		2.9		3.5		4.7	ns		
t <sub>DCLK2LE</sub>		2.1		2.5		3.4	ns		
t <sub>SAMELAB</sub>		0.1		0.1		0.2	ns		
t <sub>SAMEROW</sub>		1.1		1.1		1.5	ns		
t <sub>SAMECOLUMN</sub>		0.8		1.0		1.3	ns		
t <sub>DIFFROW</sub>		1.9		2.1		2.8	ns		
t <sub>TWOROWS</sub>		3.0		3.2		4.3	ns		
t <sub>LEPERIPH</sub>		3.1		3.3		3.7	ns		
t <sub>LABCARRY</sub>		0.1		0.1		0.2	ns		
t <sub>LABCASC</sub>		0.3		0.3		0.5	ns		

Tables 52 through 58 show EPF10K130E device internal and external timing parameters.

Table 52. EPF10	Table 52. EPF10K130E Device LE Timing Microparameters       Note (1)									
Symbol	-1 Speed Grade		-2 Spee	-2 Speed Grade		ed Grade	Unit			
	Min	Max	Min	Мах	Min	Мах				
t <sub>LUT</sub>		0.6		0.9		1.3	ns			
t <sub>CLUT</sub>		0.6		0.8		1.0	ns			
t <sub>RLUT</sub>		0.7		0.9		0.2	ns			
t <sub>PACKED</sub>		0.3		0.5		0.6	ns			
t <sub>EN</sub>		0.2		0.3		0.4	ns			
t <sub>CICO</sub>		0.1		0.1		0.2	ns			
t <sub>CGEN</sub>		0.4		0.6		0.8	ns			
t <sub>CGENR</sub>		0.1		0.1		0.2	ns			
t <sub>CASC</sub>		0.6		0.9		1.2	ns			
t <sub>C</sub>		0.3		0.5		0.6	ns			
t <sub>CO</sub>		0.5		0.7		0.8	ns			
t <sub>COMB</sub>		0.3		0.5		0.6	ns			
t <sub>SU</sub>	0.5		0.7		0.8		ns			
t <sub>H</sub>	0.6		0.7		1.0		ns			
t <sub>PRE</sub>		0.9		1.2		1.6	ns			
t <sub>CLR</sub>		0.9		1.2		1.6	ns			
t <sub>CH</sub>	1.5		1.5		2.5		ns			
t <sub>CL</sub>	1.5		1.5		2.5		ns			

 Table 53. EPF10K130E Device IOE Timing Microparameters
 Note (1)

Symbol	-1 Speed Grade		-2 Spee	d Grade	-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
t <sub>IOD</sub>		1.3		1.5		2.0	ns
t <sub>IOC</sub>		0.0		0.0		0.0	ns
t <sub>IOCO</sub>		0.6		0.8		1.0	ns
t <sub>IOCOMB</sub>		0.6		0.8		1.0	ns
t <sub>IOSU</sub>	1.0		1.2		1.6		ns
t <sub>IOH</sub>	0.9		0.9		1.4		ns
t <sub>IOCLR</sub>		0.6		0.8		1.0	ns
t <sub>OD1</sub>		2.8		4.1		5.5	ns
t <sub>OD2</sub>		2.8		4.1		5.5	ns

Table 56. EPF10K130E Device Interconnect Timing Microparameters       Note (1)									
Symbol	-1 Spee	ed Grade	-2 Spee	d Grade	-3 Spee	ed Grade	Unit		
	Min	Max	Min	Max	Min	Max			
t <sub>DIN2IOE</sub>		2.8		3.5		4.4	ns		
t <sub>DIN2LE</sub>		0.7		1.2		1.6	ns		
t <sub>DIN2DATA</sub>		1.6		1.9		2.2	ns		
t <sub>DCLK2IOE</sub>		1.6		2.1		2.7	ns		
t <sub>DCLK2LE</sub>		0.7		1.2		1.6	ns		
t <sub>SAMELAB</sub>		0.1		0.2		0.2	ns		
t <sub>SAMEROW</sub>		1.9		3.4		5.1	ns		
t <sub>SAMECOLUMN</sub>		0.9		2.6		4.4	ns		
t <sub>DIFFROW</sub>		2.8		6.0		9.5	ns		
t <sub>TWOROWS</sub>		4.7		9.4		14.6	ns		
t <sub>LEPERIPH</sub>		3.1		4.7		6.9	ns		
t <sub>LABCARRY</sub>		0.6		0.8		1.0	ns		
t <sub>LABCASC</sub>		0.9		1.2		1.6	ns		

Table 57. EPF10k	(130E Extern	al Timing Pa	arameters	Notes (1),	(2)		
Symbol	-1 Spee	ed Grade	-2 Spee	-2 Speed Grade		d Grade	Unit
	Min	Max	Min	Max	Min	Max	
t <sub>DRR</sub>		9.0		12.0		16.0	ns
t <sub>INSU</sub> (3)	1.9		2.1		3.0		ns
t <sub>INH</sub> (3)	0.0		0.0		0.0		ns
t <sub>оитсо</sub> (3)	2.0	5.0	2.0	7.0	2.0	9.2	ns
t <sub>INSU</sub> (4)	0.9		1.1		-		ns
t <sub>INH</sub> (4)	0.0		0.0		-		ns
t <sub>OUTCO</sub> (4)	0.5	4.0	0.5	6.0	-	-	ns
t <sub>PCISU</sub>	3.0		6.2		-		ns
t <sub>PCIH</sub>	0.0		0.0		-		ns
t <sub>PCICO</sub>	2.0	6.0	2.0	6.9	-	-	ns

Table 58. EPF10K	130E Extern	al Bidirectio	nal Timing	Parameters	Notes (	(1), (2)	
Symbol	-1 Spee	ed Grade	-2 Spee	d Grade	-3 Spee	ed Grade	Unit
	Min	Max	Min	Max	Min	Max	
t <sub>INSUBIDIR</sub> (3)	2.2		2.4		3.2		ns
t <sub>INHBIDIR</sub> (3)	0.0		0.0		0.0		ns
t <sub>INSUBIDIR</sub> (4)	2.8		3.0		-		ns
t <sub>INHBIDIR</sub> (4)	0.0		0.0		-		ns
toutcobidir (3)	2.0	5.0	2.0	7.0	2.0	9.2	ns
t <sub>XZBIDIR</sub> (3)		5.6		8.1		10.8	ns
t <sub>ZXBIDIR</sub> (3)		5.6		8.1		10.8	ns
toutcobidir (4)	0.5	4.0	0.5	6.0	_	-	ns
t <sub>XZBIDIR</sub> (4)		4.6		7.1		-	ns
t <sub>ZXBIDIR</sub> (4)		4.6		7.1		-	ns

#### Notes to tables:

(1) All timing parameters are described in Tables 24 through 30 in this data sheet.

(2) These parameters are specified by characterization.

(3) This parameter is measured without the use of the ClockLock or ClockBoost circuits.

(4) This parameter is measured with the use of the ClockLock or ClockBoost circuits.

# Tables 59 through 65 show EPF10K200E device internal and external timing parameters.

Table 59. EPF10K200E Device LE Timing Microparameters (Part 1 of 2)       Note (1)									
Symbol	-1 Spee	d Grade	-2 Spee	d Grade	-3 Spee	d Grade	Unit		
	Min	Max	Min	Max	Min	Max			
t <sub>LUT</sub>		0.7		0.8		1.2	ns		
t <sub>CLUT</sub>		0.4		0.5		0.6	ns		
t <sub>RLUT</sub>		0.6		0.7		0.9	ns		
t <sub>PACKED</sub>		0.3		0.5		0.7	ns		
t <sub>EN</sub>		0.4		0.5		0.6	ns		
t <sub>CICO</sub>		0.2		0.2		0.3	ns		
t <sub>CGEN</sub>		0.4		0.4		0.6	ns		
t <sub>CGENR</sub>		0.2		0.2		0.3	ns		
t <sub>CASC</sub>		0.7		0.8		1.2	ns		
t <sub>C</sub>		0.5		0.6		0.8	ns		
t <sub>CO</sub>		0.5		0.6		0.8	ns		
t <sub>COMB</sub>		0.4		0.6		0.8	ns		
t <sub>SU</sub>	0.4		0.6		0.7		ns		

Symbol	-1 Speed Grade		-2 Spee	d Grade	-3 Spee	ed Grade	Unit
	Min	Max	Min	Max	Min	Max	
t <sub>EABDATA1</sub>		1.7		2.4		3.2	ns
t <sub>EABDATA2</sub>		0.4		0.6		0.8	ns
t <sub>EABWE1</sub>		1.0		1.4		1.9	ns
t <sub>EABWE2</sub>		0.0		0.0		0.0	ns
t <sub>EABRE1</sub>		0.0		0.0		0.0	
t <sub>EABRE2</sub>		0.4		0.6		0.8	
t <sub>EABCLK</sub>		0.0		0.0		0.0	ns
t <sub>EABCO</sub>		0.8		1.1		1.5	ns
t <sub>EABBYPASS</sub>		0.0		0.0		0.0	ns
t <sub>EABSU</sub>	0.7		1.0		1.3		ns
t <sub>EABH</sub>	0.4		0.6		0.8		ns
t <sub>EABCLR</sub>	0.8		1.1		1.5		
t <sub>AA</sub>		2.0		2.8		3.8	ns
t <sub>WP</sub>	2.0		2.8		3.8		ns
t <sub>RP</sub>	1.0		1.4		1.9		
t <sub>WDSU</sub>	0.5		0.7		0.9		ns
t <sub>WDH</sub>	0.1		0.1		0.2		ns
t <sub>WASU</sub>	1.0		1.4		1.9		ns
t <sub>WAH</sub>	1.5		2.1		2.9		ns
t <sub>RASU</sub>	1.5		2.1		2.8		
t <sub>RAH</sub>	0.1		0.1		0.2		
t <sub>WO</sub>		2.1		2.9		4.0	ns
t <sub>DD</sub>		2.1		2.9		4.0	ns
t <sub>EABOUT</sub>		0.0		0.0		0.0	ns
t <sub>EABCH</sub>	1.5		2.0		2.5		ns
t <sub>EABCL</sub>	1.5		2.0		2.5		ns

Table 74. EPF10K	200S Device	e IOE Timing	n Microparai	meters (Par	t 2 of 2)	Note (1)	
Symbol	-1 Spee	d Grade	-2 Spee	d Grade	-3 Spee	d Grade	Unit
	Min	Max	Min	Max	Min	Max	
t <sub>ZX2</sub>		4.5		4.8		6.6	ns
t <sub>ZX3</sub>		6.6		7.6		10.1	ns
t <sub>INREG</sub>		3.7		5.7		7.7	ns
t <sub>IOFD</sub>		1.8		3.4		4.0	ns
t <sub>INCOMB</sub>		1.8		3.4		4.0	ns

Symbol	-1 Speed Grade		-2 Spee	ed Grade	-3 Spee	ed Grade	Unit
	Min	Max	Min	Max	Min	Мах	
t <sub>EABDATA1</sub>		1.8		2.4		3.2	ns
t <sub>EABDATA1</sub>		0.4		0.5		0.6	ns
t <sub>EABWE1</sub>		1.1		1.7		2.3	ns
t <sub>EABWE2</sub>		0.0		0.0		0.0	ns
t <sub>EABRE1</sub>		0		0		0	ns
t <sub>EABRE2</sub>		0.4		0.5		0.6	ns
t <sub>EABCLK</sub>		0.0		0.0		0.0	ns
t <sub>EABCO</sub>		0.8		0.9		1.2	ns
t <sub>EABBYPASS</sub>		0.0		0.1		0.1	ns
t <sub>EABSU</sub>	0.7		1.1		1.5		ns
t <sub>EABH</sub>	0.4		0.5		0.6		ns
t <sub>EABCLR</sub>	0.8		0.9		1.2		ns
t <sub>AA</sub>		2.1		3.7		4.9	ns
t <sub>WP</sub>	2.1		4.0		5.3		ns
t <sub>RP</sub>	1.1		1.1		1.5		ns
tWDSU	0.5		1.1		1.5		ns
t <sub>WDH</sub>	0.1		0.1		0.1		ns
t <sub>WASU</sub>	1.1		1.6		2.1		ns
t <sub>WAH</sub>	1.6		2.5		3.3		ns
t <sub>RASU</sub>	1.6		2.6		3.5		ns
t <sub>RAH</sub>	0.1		0.1		0.2		ns
t <sub>WO</sub>		2.0		2.4		3.2	ns
t <sub>DD</sub>		2.0		2.4		3.2	ns
t <sub>EABOUT</sub>		0.0		0.1		0.1	ns
t <sub>EABCH</sub>	1.5		2.0		2.5		ns
t <sub>EABCL</sub>	2.1		2.8		3.8		ns

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